## NSN 5961-01-137-9317

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View Online at https://aerobasegroup.com/nsn/5961-01-137-9317 **Inclosure Material:** Metal **Overall Length:** 1.550 inches **Overall Height:** 0.330 inches **Overall Width:** 1.050 inches **Mounting Facility Quantity:** 2 **Internal Configuration:** Junction contact-darlington connected **Electrode Internally-electrically Connected To Case:** Collector **Internal Junction Configuration:** Pnp **Mounting Method:** Unthreaded hole **Features Provided:** Burn in and hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: -120.0 collector to emitter voltage/static/base open and -120.0 collector to base voltage/static/emitter open and -5.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** -50.00 amperes collector current, dc and -2.00 amperes base current, dc **Power Rating Per Characteristic:** 300.0 watts total device dissipation **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Special Features:** Transistor **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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